# Triple 2-3-2-Input OR/NOR Gate

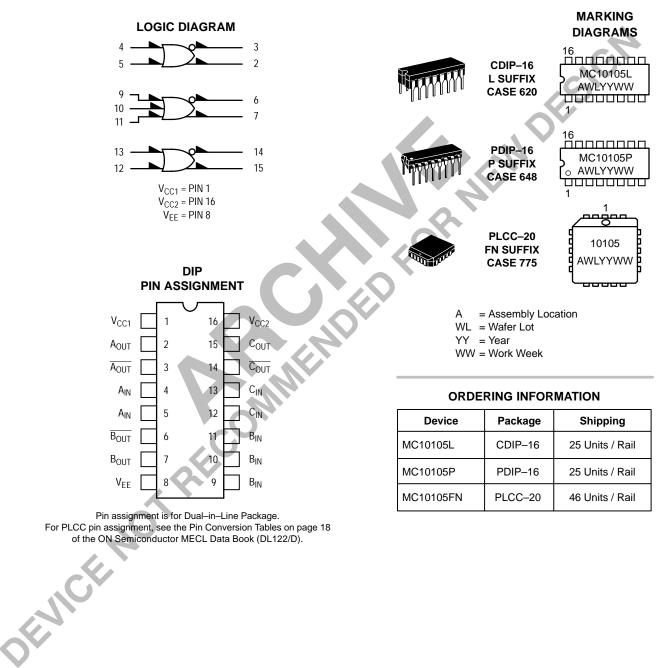
The MC10105 is a triple 2–3–2 input OR/NOR gate.

- $P_D = 30 \text{ mW typ/gate (No Load)}$
- $t_{pd} = 2.0 \text{ ns typ}$
- $t_r$ ,  $t_f = 2.0$  ns typ (20%-80%)



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### **ELECTRICAL CHARACTERISTICS**

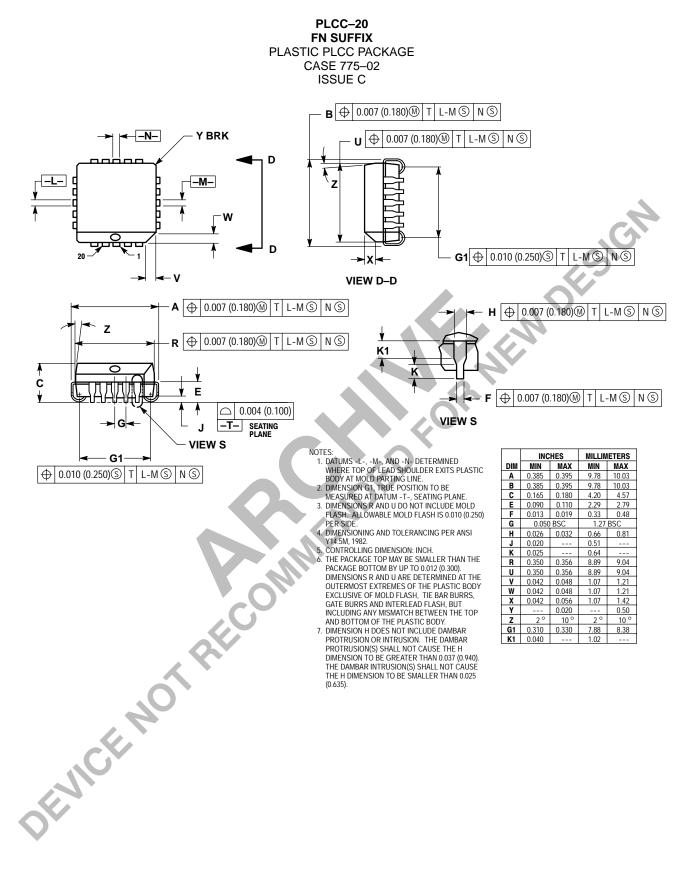
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Characteristic		<b>D</b> <sup>1</sup>				Test Limits	•	1		-
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	Characteristic		Pin Under	-30	D°C		+25°C		+85	5°C	
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		Symbol		Min	Max	Min	Тур	Max	Min	Max	Un
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Power Supply Drain Current	١ <sub>E</sub>	8		23		17	21		23	mAc
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	Input Current	I <sub>inH</sub>	4		425			265		265	μAd
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$			4	0.5		0.5			0.3		μAd
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	Output Voltage Logic 1										Vdo
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	Output Voltage Logic 0	V <sub>OL</sub>									Vde
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Threshold Voltage Logic 1	V <sub>OHA</sub>									Vd
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Threshold Voltage Logic 0	V <sub>OLA</sub>								-1.595 -1.595	Vdo
table <th< td=""><td>Switching Times (50<math>\Omega</math> Load)</td><td></td><td></td><td></td><td></td><td></td><td></td><td></td><td></td><td></td><td>ns</td></th<>	Switching Times (50 $\Omega$ Load)										ns
t2+ 2 1.1 3.6 1.1 2.0 3.3 1.1 3.7   Fall Time (20 to 80%) $t_{3-}$ 3 1.1 3.6 1.1 2.0 3.3 1.1 3.7   L $t_{2-}$ 2 1.1 3.6 1.1 2.0 3.3 1.1 3.7   L $t_{2-}$ 2 1.1 3.6 1.1 2.0 3.3 1.1 3.7	Propagation Delay	t <sub>4–3+</sub> t <sub>4+2+</sub>	3 2	1.0 1.0	3.1 3.1	1.0 1.0	2.0 2.0	2.9 2.9	1.0 1.0	3.3 3.3	
t <sub>2</sub> 2 1.1 3.6 1.1 2.0 3.3 1.1 3.7	Rise Time (20 to 80%)										
	Fall Time (20 to 80%)										
		5	2		ND						
	of Mot N										

#### ELECTRICAL CHARACTERISTICS (continued)

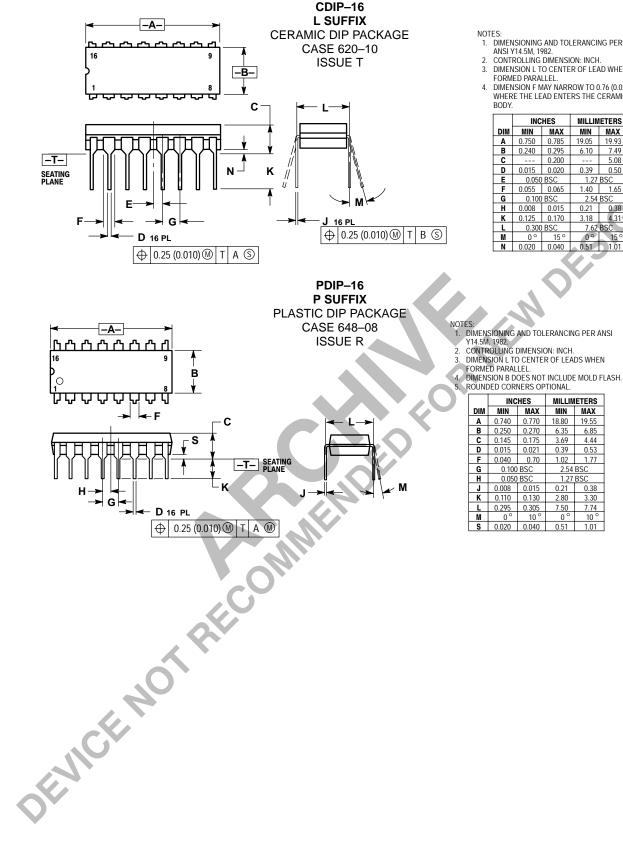
					TEST VOI	TAGE VALU	IES (Volts)		
		@ Test Te	mperature	V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	V <sub>EE</sub>	
			–30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
			Pin	TEST V	OLTAGE AP	PLIED TO PI	NS LISTED I	BELOW	<i></i>
Character	istic	Symbol	Under Test	V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	V <sub>EE</sub>	(V <sub>CC</sub> ) Gnd
Power Supply Drain	Current	Ι <sub>Ε</sub>	8					8	1, 16
Input Current		l <sub>inH</sub>	4	4				8	1, 16
		I <sub>inL</sub>	4		4			8	1, 16
Output Voltage	Logic 1	V <sub>OH</sub>	3 2	4				8 8	1, 16 1, 16
Output Voltage	Logic 0	V <sub>OL</sub>	3 2	4				8 8	1, 16 1, 16
Threshold Voltage	Logic 1	V <sub>OHA</sub>	3 2			4	4	8 8	1, 16 1, 16
Threshold Voltage	Logic 0	V <sub>OLA</sub>	3 2			4	4	8 8	1, 16 1, 16
Switching Times	(50 $\Omega$ Load)					Pulse In	Pulse Out	–3.2 V	+2.0 V
Propagation Delay		t <sub>4+3-</sub> t <sub>4-3+</sub> t <sub>4+2+</sub> t <sub>4-2-</sub>	3 3 2 2			4 4 4 4	3 3 2 2	8 8 8 8	1, 16 1, 16 1, 16 1, 16 1, 16
Rise Time	(20 to 80%)	t <sub>3+</sub> t <sub>2+</sub>	3 2			4 4	3 2	8 8	1, 16 1, 16
Fall Time	(20 to 80%)	t <sub>3-</sub> t <sub>2-</sub>	3 2			4 4	3 2	8 8	1, 16 1, 16

te terminated through a 50-ohm resistor to -2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the area manner.

#### PACKAGE DIMENSIONS



### PACKAGE DIMENSIONS



DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEAD WHEN

FORMED PARALLEL DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC

	INCHES		MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.750	0.785	19.05	19.93		
В	0.240	0.295	6.10	7.49		
С		0.200		5.08		
D	0.015	0.020	0.39	0.50		
E	0.050	BSC	1.27	BSC		
F	0.055	0.065	1.40	1.65		
G	0.100	BSC	2.54	BSC		
Н	0.008	0.015	0.21	0.38		
Κ	0.125	0.170	3.18	4.31		
L	0.300	BSC	7.62	BSC		
Μ	0 °	15 °	0 °	15°		
Ν	0.020	0.040	0.51	1.01		

MILLIMETERS

MIN MAX

6.85

4.44

0.53

1.77

3.30

7.74

1.01

10

18.80 19.55

2.54 BSC

1.27 BSC

0.21 0.38

6.35

3.69

0.39

1.02

2.80

7.50

0

0.51

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## **Notes**

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